

NPN-Si-Fototransistor mit V_λ Charakteristik
Silicon NPN Phototransistor with V_λ Characteristics
Lead (Pb) Free Product - RoHS Compliant

SFH 3310



Wesentliche Merkmale

- Speziell geeignet für Anwendungen im Bereich von 350 nm bis 970 nm
- Angepasst an die Augenempfindlichkeit (V_λ)

Anwendungen

- Umgebungslicht-Detektor
- Beleuchtungsmesser
- Dimmungssensor für Hintergrundbeleuchtung
- „Messen/Steuern/Regeln“

Features

- Especially suitable for applications from 350 nm to 970 nm
- Adapted to human eye sensitivity (V_λ)

Applications

- Ambient light detector
- Exposure meter for daylight and artificial light
- Sensor for Backlight-Dimming
- For control and drive circuits

Typ Type	Bestellnummer Ordering Code	Fotostrom , $E_e = 10\mu\text{W}/\text{cm}^2$, $\lambda = 560\text{nm}$, $V_{\text{CE}} = 5\text{ V}$ Photocurrent $I_{\text{pce}} (\mu\text{A})$
SFH 3310	Q65110A5343	2.5...8.0

Grenzwerte ($T_A = 25\text{ °C}$)**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}; T_{stg}$	- 40 ... + 100	°C
Kollektor-Emitterspannung Collector-emitter voltage	V_{CE}	5.5	V
Kollektorstrom Collector current	I_C	20	mA
Emitter-Kollektorspannung Emitter-collector voltage	V_{EC}	0.5	V

Kennwerte ($T_A = 25\text{ °C}$)**Characteristics**

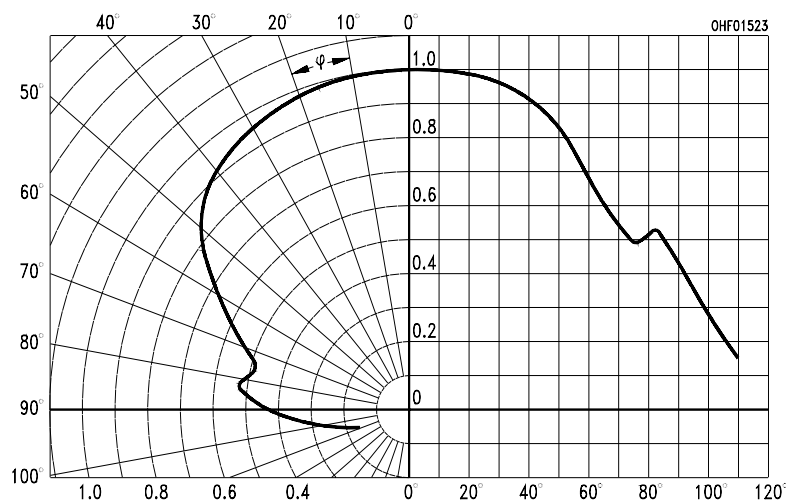
Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	λ_{Smax}	570	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von S_{max} Spectral range of sensitivity $S = 10\%$ of S_{max}	λ	350 ... 970	nm
Bestrahlungsempfindliche Fläche Radiant sensitive area	A	0.29	mm ²
Abmessung der Chipfläche Dimensions of chip area	$L \times B$ $L \times W$	0.75 × 0.75	mm × mm
Halbwinkel Half angle	φ	± 75	Grad. deg.
Kapazität, $V_{CE} = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ Capacitance	C_{CE}	16	pF
Dunkelstrom Dark current $V_R = 5\text{ V}$	I_{CEO}	3 (< 50)	nA

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit
		-2	-3	
Fotostrom Photocurrent $E_e = 10\mu\text{W}/\text{cm}^2$, $\lambda = 560\text{nm}$, $V_{\text{CE}} = 5\text{V}$ $E_v = 1000\text{lx}$, Normlicht/Standard light A	I_{PCE}	2.5...5.0 290	4.0...8.0 460	μA μA
Kollektor-Emitter-Sättigungsspannung Collector-emitter saturation voltage $I_{\text{C}} = I_{\text{PCEmin}}^{1)} \times 0.3$, $E_e = 10\mu\text{W}/\text{cm}^2$, $\lambda = 560\text{nm}$	V_{CEsat}	100	100	mV

1) I_{PCEmin} ist der minimale Fotostrom der jeweiligen Gruppe

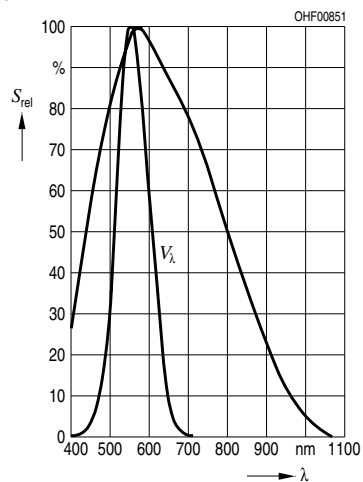
1) I_{PCEmin} is the min. photocurrent of the specified group

Directional Characteristics $S_{\text{rel}} = f(\varphi)$



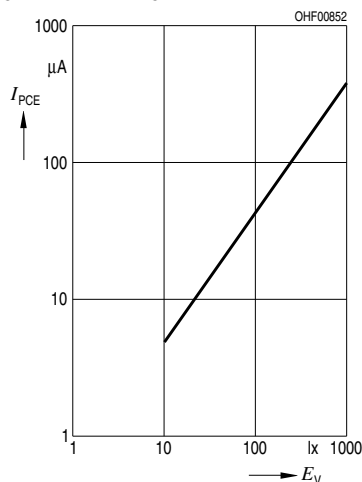
Relative Spectral Sensitivity

$S_{rel} = f(\lambda)$



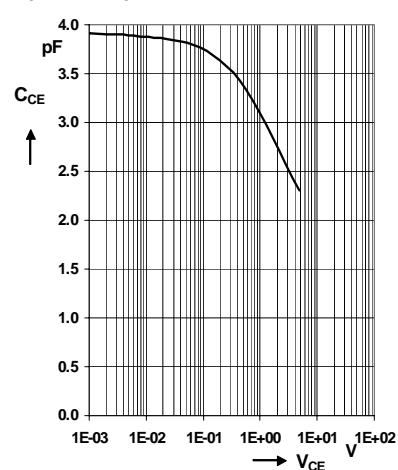
Photocurrent

$I_{PCE} = f(E_V), V_{CE} = 5 V$



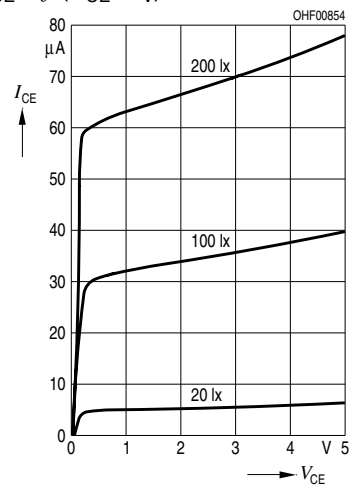
Collector-Emitter Capacitance

$C_{CE} = f(V_{CE})$



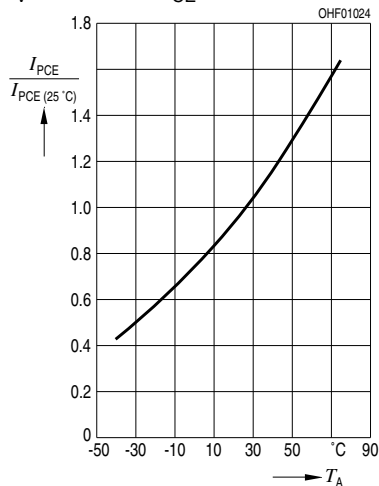
Collector-Emitter Current

$I_{CE} = f(V_{CE}; E_V)$

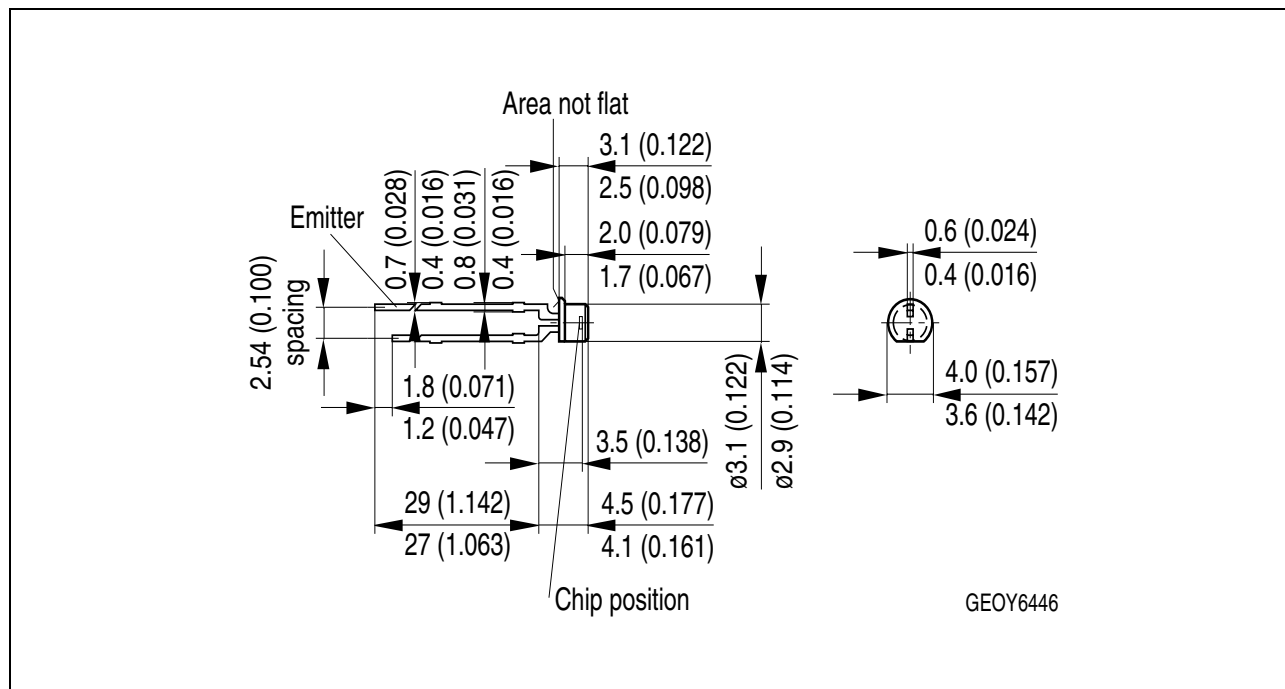


Photocurrent $I_{PCE}/I_{PCE(25^\circ C)} = f(T_A)$

$E_V = 1000 \text{ lx}, V_{CE} = 1 V \dots 5 V$



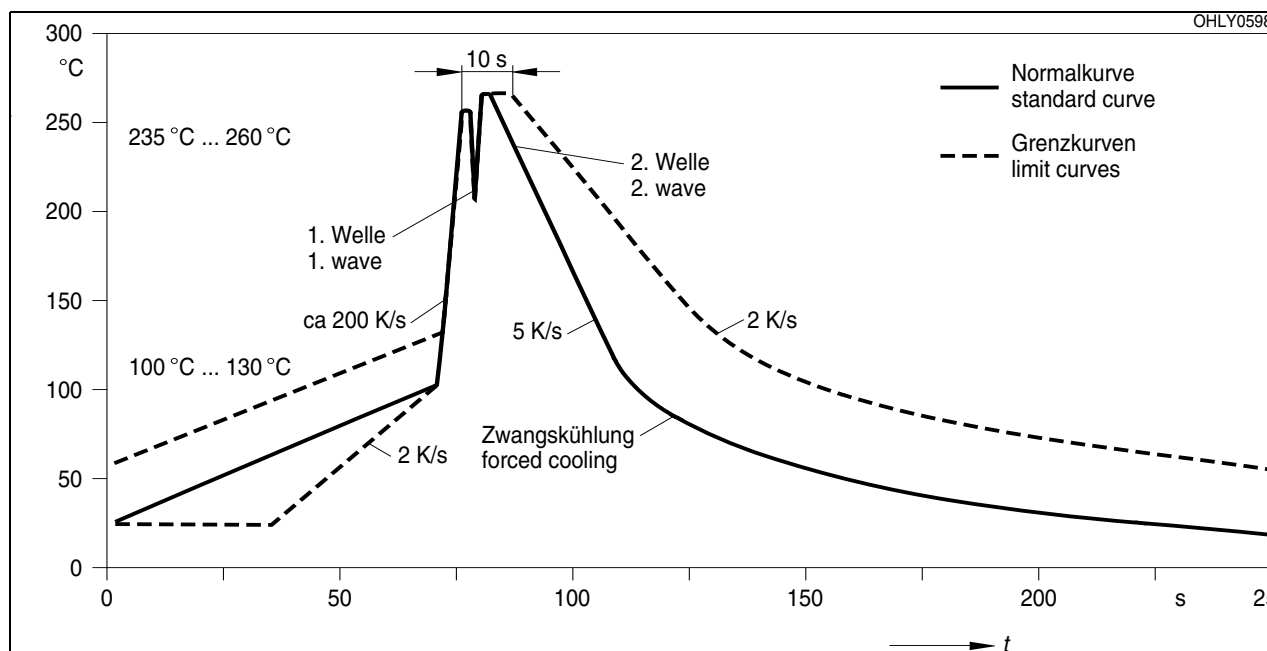
**Maßzeichnung
Package Outlines**



Maße in mm (inch) / Dimensions in mm (inch).

**Lötbedingungen
Soldering Conditions
Wellenlöten (TTW)
TTW Soldering**

(nach CECC 00802)
(acc. to CECC 00802)



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EU RoHS and China RoHS compliant product



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